



THE UNITED STATES PATENT AND TRADEMARK OFFICE

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In re the Application of:

ONO, Toshiaki et al.

Group Art Unit: 1765

Serial No.: 09/883,922

Examiner: ANDERSON, M.

Filed: **June 20, 2001**

P.T.O. Confirmation No.: 3735

For: **METHOD OF MANUFACTURING EPITAXIAL WAFER AND METHOD OF
PRODUCING SINGLE CRYSTAL AS MATERIAL THEREFOR**

AMENDMENT UNDER 37 CFR §1.111

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

June 20, 2003

Sir:

In response to the Office Action dated February 26, 2003, please amend the above-identified application as follows: